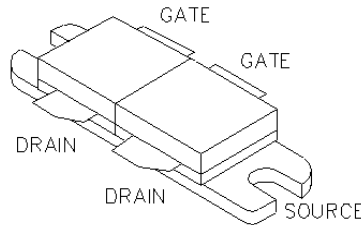




**General Description**

Silicon VDMOS and LDMOS transistors designed specifically for broadband RF applications. Suitable for Military Radios, Cellular and Paging Amplifier Base Stations, Broadcast FM/AM, MRI, Laser Driver and others.

"Polyfet"<sup>TM</sup> process features gold metal for greatly extended lifetime. Low output capacitance and high  $F_t$  enhance broadband performance



**PATENTED GOLD METALIZED SILICON GATE ENHANCEMENT MODE RF POWER VDMOS TRANSISTOR**

**200 Watts Gemini**

**Package Style AH**

**HIGH EFFICIENCY, LINEAR, HIGH GAIN, LOW NOISE**

**ABSOLUTE MAXIMUM RATINGS (TC = 25 °C)**

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	DC Drain Current	Drain to Gate Voltage	Drain to Source Voltage	Gate to Source Voltage
350 Watts	0.5 °C/W	200 °C	-65 °C to 150 °C	16 A	70 V	70V	30V

**RF CHARACTERISTICS ( 200WATTS OUTPUT )**

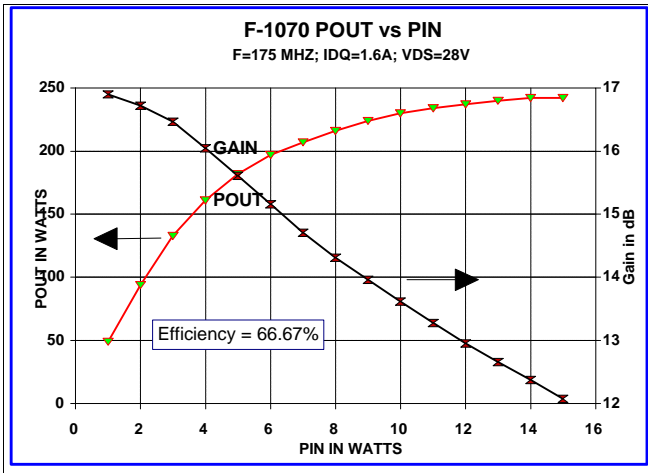
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	13			dB	Idq = 1.6 A, Vds = 28.0V, F = 175 MHz
$\eta$	Drain Efficiency		60		%	Idq = 1.6 A, Vds = 28.0V, F = 175 MHz
VSWR	Load Mismatch Tolerance			20:1	Relative	Idq = 1.6 A, Vds = 28.0V, F = 175 MHz

**ELECTRICAL CHARACTERISTICS (EACH SIDE)**

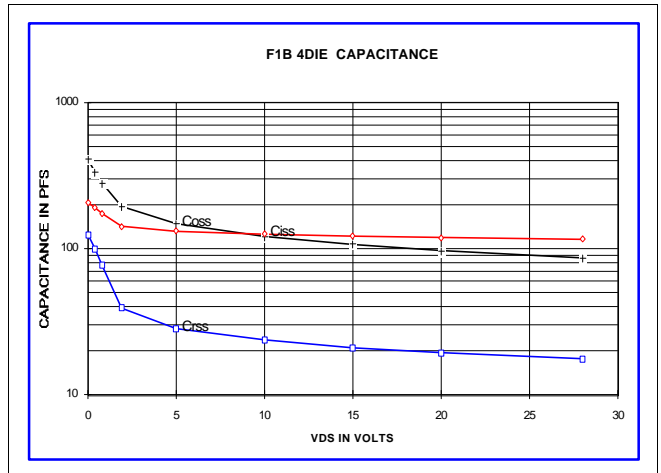
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltage	65			V	Ids = 0.2 A, Vgs = 0V
Idss	Zero Bias Drain Current			4	mA	Vds = 28.0 V, Vgs = 0V
Igss	Gate Leakage Current			1	uA	Vds = 0 V, Vgs = 30V
Vgs	Gate Bias for Drain Current	1		7	V	Ids = 0.4 A, Vgs = Vds
gM	Forward Transconductance		3.2		Mho	Vds = 10V, Vgs = 5V
Rdson	Saturation Resistance		0.35		Ohm	Vgs = 20V, Ids = 16A
Idsat	Saturation Current		22		Amp	Vgs = 20V, Vds = 10V
Ciss	Common Source Input Capacitance		132		pF	Vds = 28.0 V, Vgs = 0V, F = 1 MHz
Crss	Common Source Feedback Capacitance		16		pF	Vds = 28.0 V, Vgs = 0V, F = 1 MHz
Coss	Common Source Output Capacitance		80		pF	Vds = 28.0 V, Vgs = 0V, F = 1 MHz

# F1070

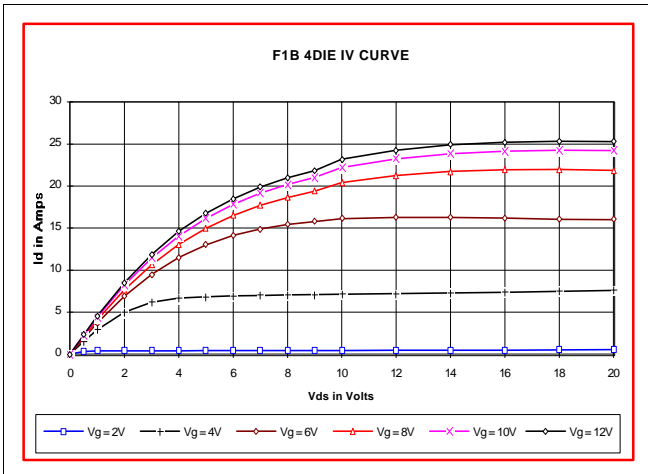
POUT VS PIN GRAPH



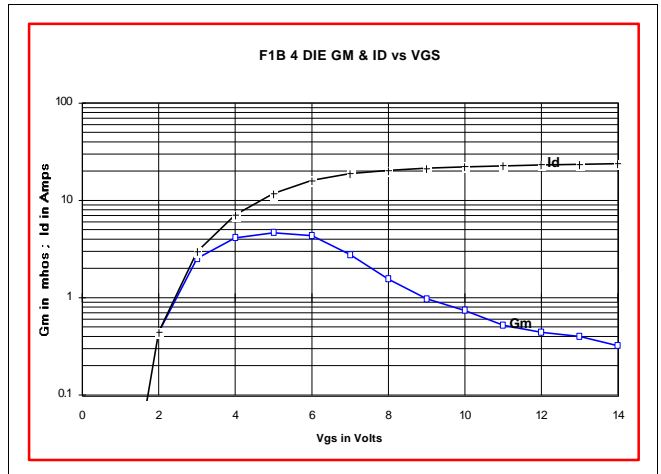
CAPACITANCE VS VOLTAGE



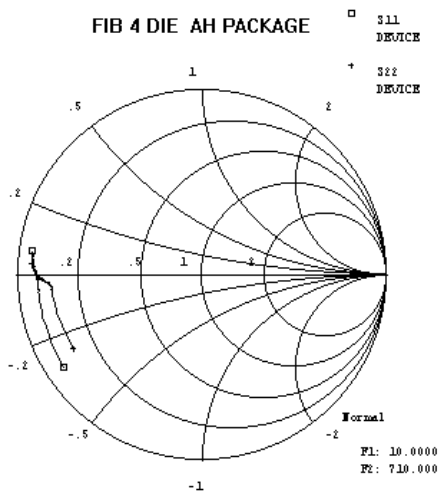
IV CURVE



ID AND GM VS VGS



S11 AND S22 SMITH CHART



PACKAGE DIMENSIONS IN INCHES

